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## <u>Boundary Conditions on</u> <u>Perfect Conductors</u>

Consider the case where region 2 is a **perfect conductor**:

 $\mathbf{E}_{1}(\bar{\mathbf{r}})$ 

 $\mathcal{E}_1$   $\hat{a}_n \bigwedge$ 

 $\mathbf{E}_{2}(\overline{\mathbf{r}})=\mathbf{0}$ 

$$\sigma_2 = \infty$$
 (i.e., perfect conductor)

Recall  $\mathbf{E}(\overline{\mathbf{r}}) = 0$  in a perfect conductor. This of course means that **both** the tangential and normal component of  $\mathbf{E}_2(\overline{\mathbf{r}})$  are also equal to **zero**:

$$\mathbf{E}_{2t}\left(\overline{\mathbf{r}}\right) = \mathbf{0} = \mathbf{E}_{2n}\left(\overline{\mathbf{r}}\right)$$

And, since the **tangential** component of the electric field is **continuous** across the boundary, we find that **at the interface**:

$$\mathbf{E}_{1t}\left(\overline{r_{b}}\right) = \mathbf{E}_{2t}\left(\overline{r_{b}}\right) = \mathbf{0}$$

Think about what this means! The **tangential** vector component in the dielectric (at the dielectric/conductor boundary) is **zero**. Therefore, the electric field **at the boundary** only has a **normal** component:

$$\mathsf{E}_{1}(\overline{r_{b}}) = \mathsf{E}_{1n}(\overline{r_{b}})$$

Therefore, we can say:

The electric field on the surface of a perfect conductor is orthogonal (i.e., normal) to the conductor.

Q1: What about the electric flux density  $D_1(\bar{r})$ ?

A1: The relation  $D_1(\bar{r}) = \varepsilon_1 E_1(\bar{r})$  is still of course valid, so that the electric flux density at the surface of the conductor must also be orthogonal to the conductor.

**Q2:** But, we learned that the **normal** component of the **electric flux density** is **continuous** across an interface. If  $D_{2n}(\bar{r}) = 0$ , why isn't  $D_{1n}(\bar{r}_b) = 0$ ?

A2: Great question! The answer comes from a more general form of the boundary condition.

Consider again the interface of two dissimilar dielectrics. This time, however, there is some surface charge distribution  $\rho_s(\bar{r_b})$  (i.e., free charge!) at the dielectric interface:  $\mathbf{E}_1(\bar{\mathbf{r}}), \mathbf{D}_1(\bar{\mathbf{r}})$  $\varepsilon_1 \qquad \hat{r_a} \wedge \qquad \rho_s(\bar{r_b})$  $\mathbf{E}_2(\bar{\mathbf{r}}), \mathbf{D}_2(\bar{\mathbf{r}})$ 

The boundary condition for this situation turns out to be:

$$\hat{a}_{n} \cdot \left[ \mathsf{D}_{1n} \left( \overline{r_{b}} \right) - \mathsf{D}_{2n} \left( \overline{r_{b}} \right) \right] = \rho_{s} \left( \overline{r_{b}} \right)$$
$$\mathcal{D}_{1n} \left( \overline{r_{b}} \right) - \mathcal{D}_{2n} \left( \overline{r_{b}} \right) = \rho_{s} \left( \overline{r_{b}} \right)$$

where  $D_n(\overline{r_b}) = \hat{a}_n \cdot D_n(\overline{r_b})$  is the scalar component of  $D_n(\overline{r_b})$  (note the units of each side are  $C/m^2$ !).

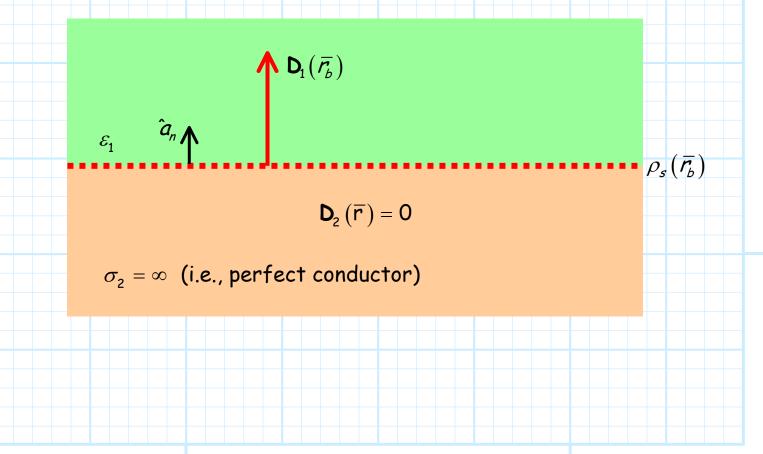
Note that if  $\rho_s(\bar{r_b}) = 0$ , this boundary condition returns (both physically and mathematically) to the case studied earlier—the **normal** component of the electric flux density is **continuous** across the interface.

This more **general** boundary condition is useful for the dielectric/conductor interface. Since  $D_2(\overline{r}) = 0$  in the conductor, we find that:

$$\hat{a}_{n} \cdot \left[ \mathsf{D}_{1n} \left( \overline{r_{b}} \right) - \mathsf{D}_{2n} \left( \overline{r_{b}} \right) \right] = \rho_{s} \left( \overline{r_{b}} \right)$$
$$\hat{a}_{n} \cdot \mathsf{D}_{1n} \left( \overline{r_{b}} \right) = \rho_{s} \left( \overline{r_{b}} \right)$$
$$\mathcal{D}_{1n} \left( \overline{r_{b}} \right) = \rho_{s} \left( \overline{r_{b}} \right)$$

In other words, the **normal** component of the **electric flux density** at the **conductor surface** is equal to the **charge density** on the conductor surface.

Note in a perfect conductor, there is **plenty** of **free** charge available to form this charge density ! Therefore, we find in **general** that  $D_{1n} \neq 0$  at the surface of a conductor.



Summarizing, the boundary conditions for the tangential components field components at a dielectric/conductor interface are:

$$\mathbf{E}_{1t}\left( \, \overline{\mathbf{r}_{b}} \, \right) = \mathbf{0}$$

$$\mathbf{D}_{1t}\left(\overline{\mathbf{r}_{b}}\right)=\mathbf{0}$$

but for the normal field components:

$$\mathcal{D}_{1n}(\bar{r_b}) = \rho_s(\bar{r_b})$$
$$\mathcal{E}_{1n}(\bar{r_b}) = \frac{\rho_s(\bar{r_b})}{\varepsilon_1}$$

Again, these boundary conditions describe the fields at the conductor/dielectric interface. They say nothing about the value of the fields at locations above this interface.